

AM Receiver Circuit

Technology: Bipolar

Features

- Controlled RF preamplifier
- Multiplicative balanced mixer
- Separate oscillator with amplitude control
- IF amplifier with gain control
- Balanced full-wave detector
- Audio preamplifier
- Internal AGC voltage
- Amplifier for field-strength indication
- Electronic stand-by on/off switch

Block Diagram / Application Circuit

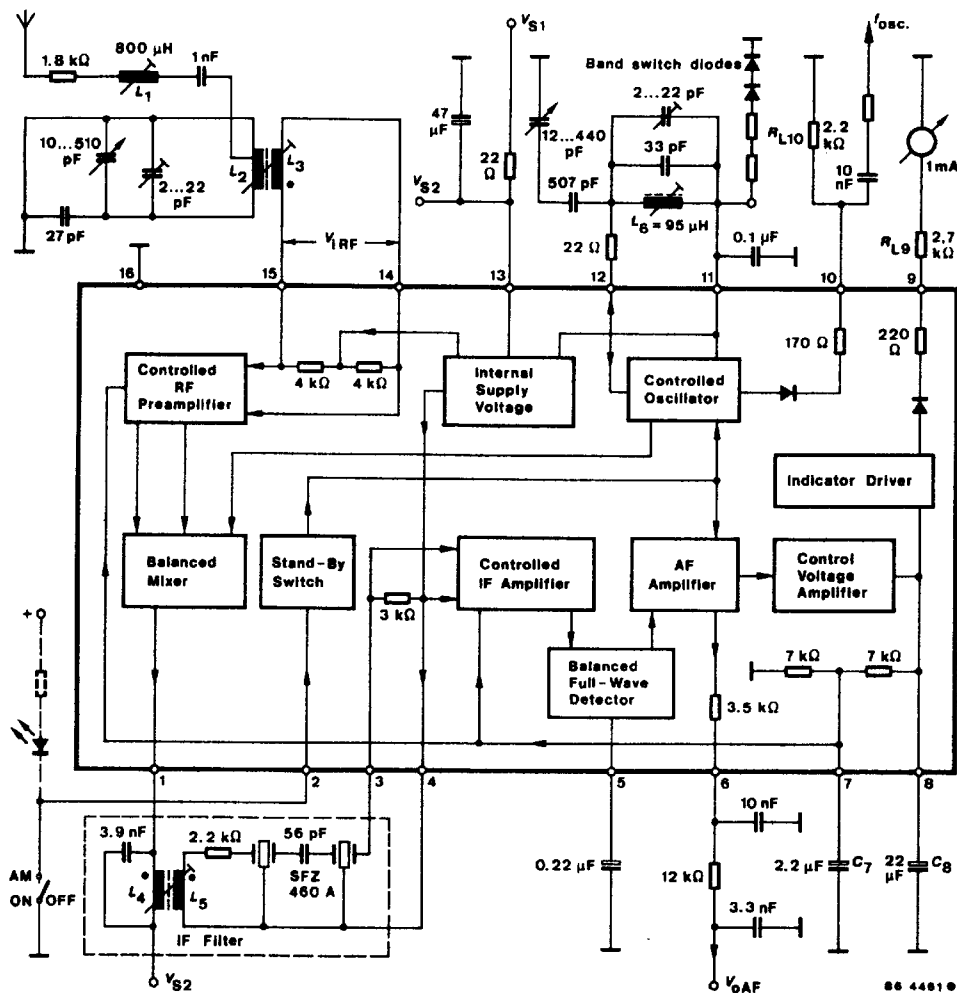


Figure 1. Block diagram and application circuit

Absolute Maximum Ratings

Reference point Pin 16, unless otherwise specified

| Parameters | | Symbol | Value | Unit |
|---------------------------------------|------------|------------------|---------------|------|
| Supply voltage | Pin 13 | V_S | 20 | V |
| Voltage on Pin 2 | | V_2 | 0 to 20 | V |
| RF inputs Voltages Reference point 15 | Pin 14 | $\pm V_{i14/15}$ | 12 | V |
| | Pin 14 | V_i | V_S | V |
| | Pin 14 | $-V_i$ | 0.6 | V |
| | Pin 15 | V_i | V_i | V |
| | Pin 15 | $-V_i$ | 0.6 | V |
| RF inputs Currents | Pin 14, 15 | $\pm I_i$ | 200 | mA |
| Ambient temperature range | | T_{amb} | - 30 to + 80 | °C |
| Storage temperature range | | T_{stg} | - 55 to + 150 | °C |

Electrical Characteristics

$V_S = 8.5$ V, reference point Pin 16, $f_{IRF} = 1$ MHz, $R_G = 50 \Omega$, $f_{mod} = 0.4$ kHz, $m = 30\%$, $f_{IF} = 460$ kHz,

$T_{amb} = +25^\circ\text{C}$, unless otherwise specified

| Parameters | Test Conditions / Pin | Symbol | Min | Type | Max | Unit |
|---|---|---------------|-----|----------------|-----|------------|
| Supply voltage range | Pin 13 | V_S | 7.5 | | 18 | V |
| Supply current | Without load, $I_L = 0$ (Pin 11) Pin 13 | I_S | | 23 | 30 | mA |
| RF preamplifier and mixer | | | | | | |
| DC input voltages | Pin 14, 15 | V_i | | $V_S/2$ | | V |
| Input impedances | $V_{iRF} < 300 \mu\text{V}$, $V_{iRF} > 10 \text{ mV}$, Pin 14, 15 | R_i | | 5.5 | | k Ω |
| | | C_i | | 25 | | pF |
| | Pin 14, 15 | R_i | | 8.0 | | k Ω |
| | | C_i | | 22 | | pF |
| Output impedance | Pin 1 | R_O | 500 | | | k Ω |
| | | C_O | | 6.0 | | pF |
| Maximum conversion conductance | I_{O1IF}/V_{iRF} | ΔS_M | | | 6.5 | mA/V |
| Maximum IF output voltage | Pin 1 | $V_{OIF(PP)}$ | | | 5.0 | V |
| Output current | Pin 1 | I_O | | 1.2 | | mA |
| Preamplifier control range | | S_M | | 30 | | dB |
| Max. RF input voltage | Pin 14, 15 | $V_{i(PP)}$ | | | 2.5 | V |
| Oscillator | | | | | | |
| Frequency range | Pin 12 | f_{OSC} | 0.6 | | 60 | MHz |
| Oscillator circuit impedance range | Pin 12 | Z_{LOSC} | 0.5 | | 200 | k Ω |
| Controlled oscillator amplitude | Pin 12 | V_{OSC} | | 130 | 150 | mV |
| DC output voltage | $I_L = 0$ V Pin 11 | V_O | | $6 V_{BE(4V)}$ | | V |
| Output load current range | Pin 11 | $-I_L$ | | | 20 | mA |
| Output resistance | $I_L = 5 \pm 0.5$ mA, Pin 11 | R_O | | 25 | | Ω |
| Oscillator frequency output Pin 10 | | | | | | |
| Output voltage | $R_{L10} = 4.7$ k Ω | $V_{O(PP)}$ | | 320 | | mV |
| Output resistance | | R_O | | 170 | | Ω |
| Allowable output current | | $I_{O(P)}$ | | | 3 | mA |

| Parameters | Test Conditions / Pin | Symbol | Min | Type | Max | Unit |
|--|---|--------------------------------|----------|--------|------------|------------------|
| IF amplifier an AF stage | | | | | | |
| DC input voltages | Pin 3, 4 | V_i | | 2 | | V |
| Input impedance | Pin 3 | R_i C_i | 2.4 | 3 7 | 3.9 | k Ω pF |
| Max. IF input voltage | m = 80%, d = 3% Pin 3 | V_i | | 90 | | mV |
| Control range | $V_{0AF} = -6$ dB | ΔV_i | | 61 | | dB |
| Audio output voltage | $V_i = 1$ mV (Pin 3), without load, Pin 6 | V_O | | 310 | | mV |
| Audio output resistance | Pin 6 | R_O | | 3.5 | | k Ω |
| Field-strength indication Pin 9 | | | | | | |
| DC indicator voltages | $R_{L9} = 2.7$ k Ω , $V_i = 0$ $R_{L9} = 2.7$ k Ω , $V_i = 500$ mV | V_O V_O | 0 2.5 | 2.8 | 140 3.1 | mV V |
| Output current capability | | $-I_O$ | 2.0 | | | mA |
| Output resistance | $-I_O = 0.5$ mA | R_O | | 220 | | Ω |
| Reverse voltage at the output | AM switch-off, $\pm I_0 \leq 1$ μ A | V_O | | 6 | | V |
| Stand-by switch Pin 2 | | | | | | |
| Switching voltage | | V_i | | 2.75 | | V |
| Required control voltage | AM ON AM OFF | V_i V_i (or open input) | 3.5 | | 2 | V |
| Input current | AM on, switching current AM off, reverse current ($V_2 = V_3$) | $-I_i$ $\pm I_i$ | | | 200 10 | μ A |

Operating Conditions

$V_S = 8.5$ V, $f_{iRF} = 1$ MHz, $f_{mod} = 0.4$ kHz, m = 30%, $T_{amb} = 25^\circ$ C, reference point Pin 16, see figure 2, unless otherwise specified

| Parameters | Test Conditions / Pin | Symbol | Min | Type | Max | Unit |
|---|--|---------------------|-----|--|-----|---------|
| RF input voltages | (S + N)/N = 6 dB = 26 dB = 46 dB | V_{iRF} | | 1.5 15 150 | | μ V |
| RF input for age operation | | V_{iRF} | | 30 | | μ V |
| Control range for (Reference value $V_i = 500$ mV) | $\Delta V_0 = 6$ dB $\Delta V_0 = 1$ dB | ΔV_{iRF} | | 91 86 | | dB |
| Maximum RF input voltage | d = 3%, m = 80% d = 3%, m = 30% d = 10%, m = 30% | V_{iRF} | | 0.5 0.7 0.9 | | V |
| Audio output voltage | $V_1 = 1$ mV $V_2 = 4$ μ V, m = 0.8 | V_{0AF} | | 310 (± 2 dB) 130 (± 3.5 dB) | | mV |
| RF input voltage | $V_{0AF} = 60$ mV | V_{iRF} | | 5.5 | | μ V |
| Total distortion of audio output voltage | m = 80%, $V_i = 1$ mV $V_i = 500$ mV | d | | 0.5 3.0 | | % |
| Signal plus noise to noise ratio of audio output voltage | $V_i = 1$ mV | $\frac{(S + N)}{N}$ | | 50 | | dB |
| IF bandwidth (-3 dB) | | B_{iF} | | 4.6 | | kHz |
| IF selectively | $\Delta f = \pm 9$ kHz $\Delta f = \pm 36$ kHz | S_{iF} | | 30 60 | | dB |

Test Circuit

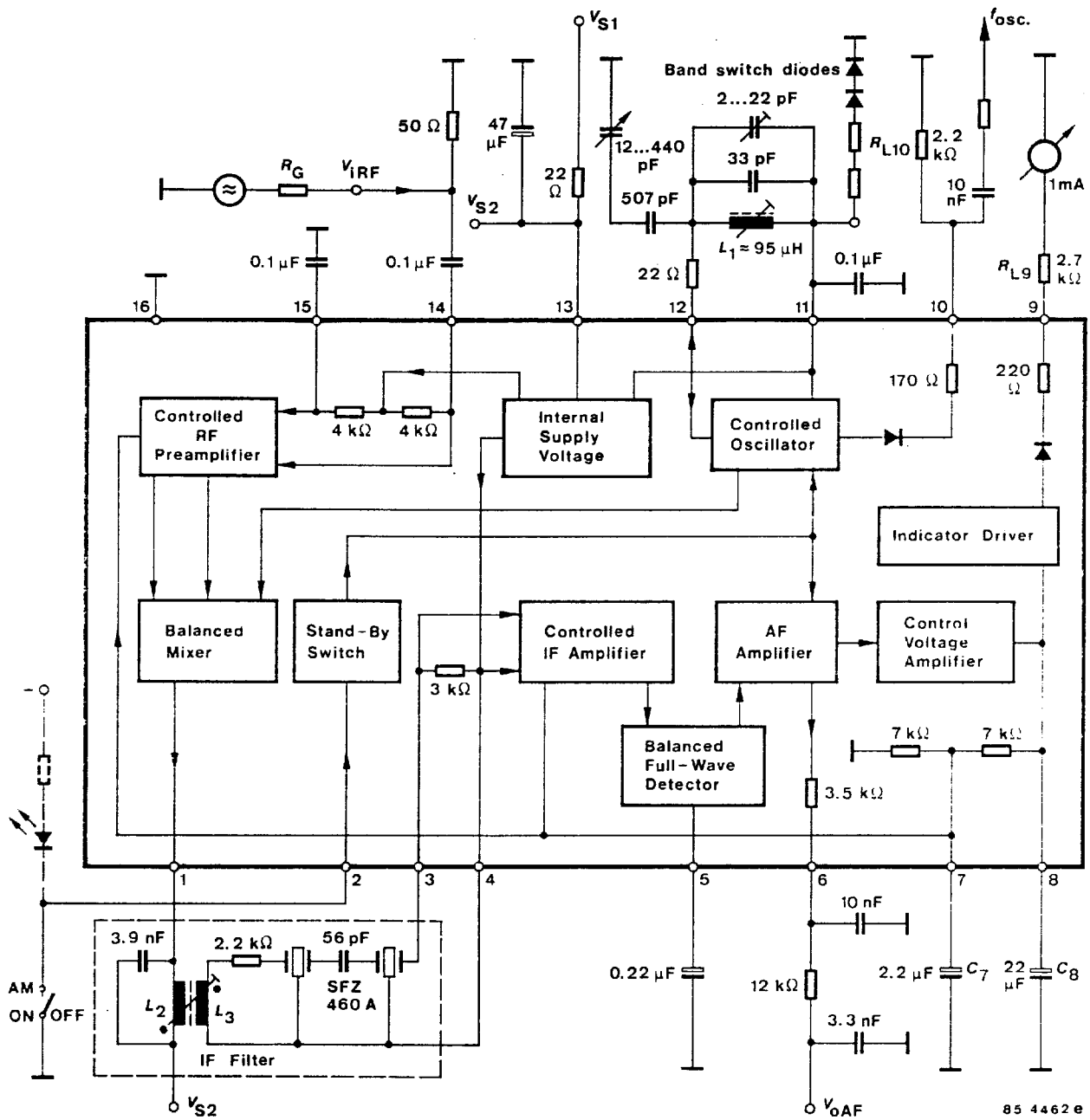


Figure 2. Test circuit

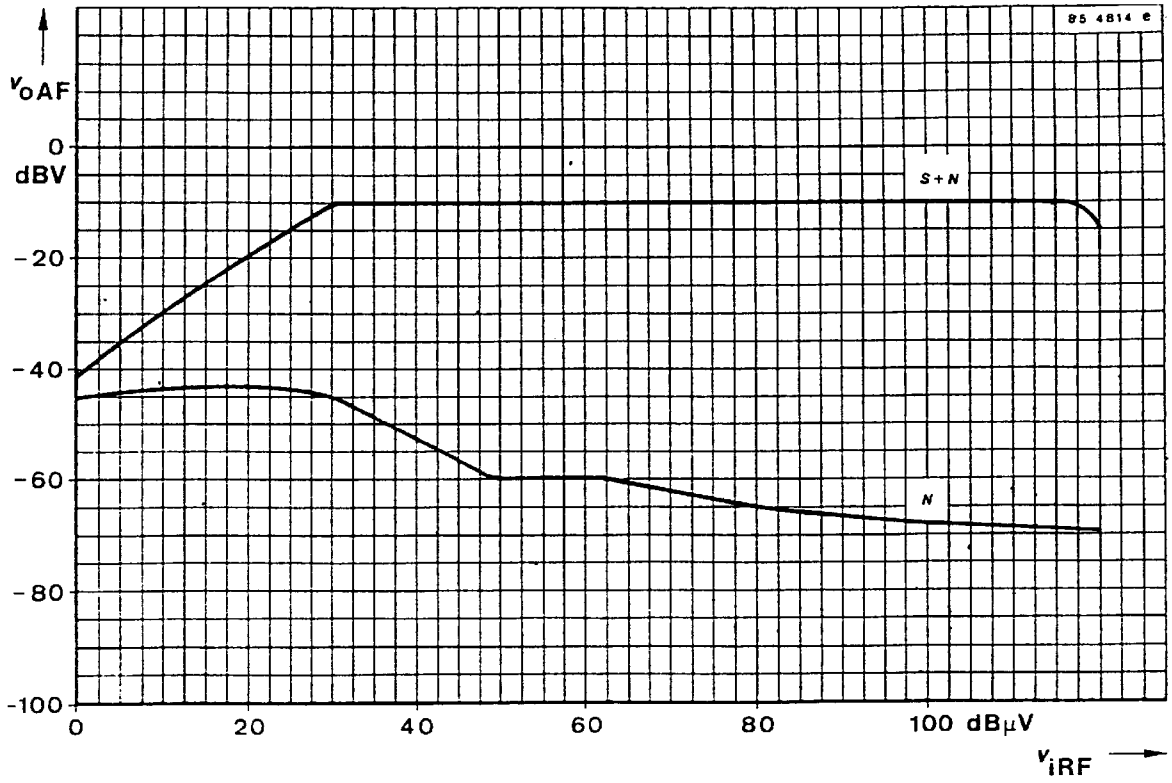


Figure 3.

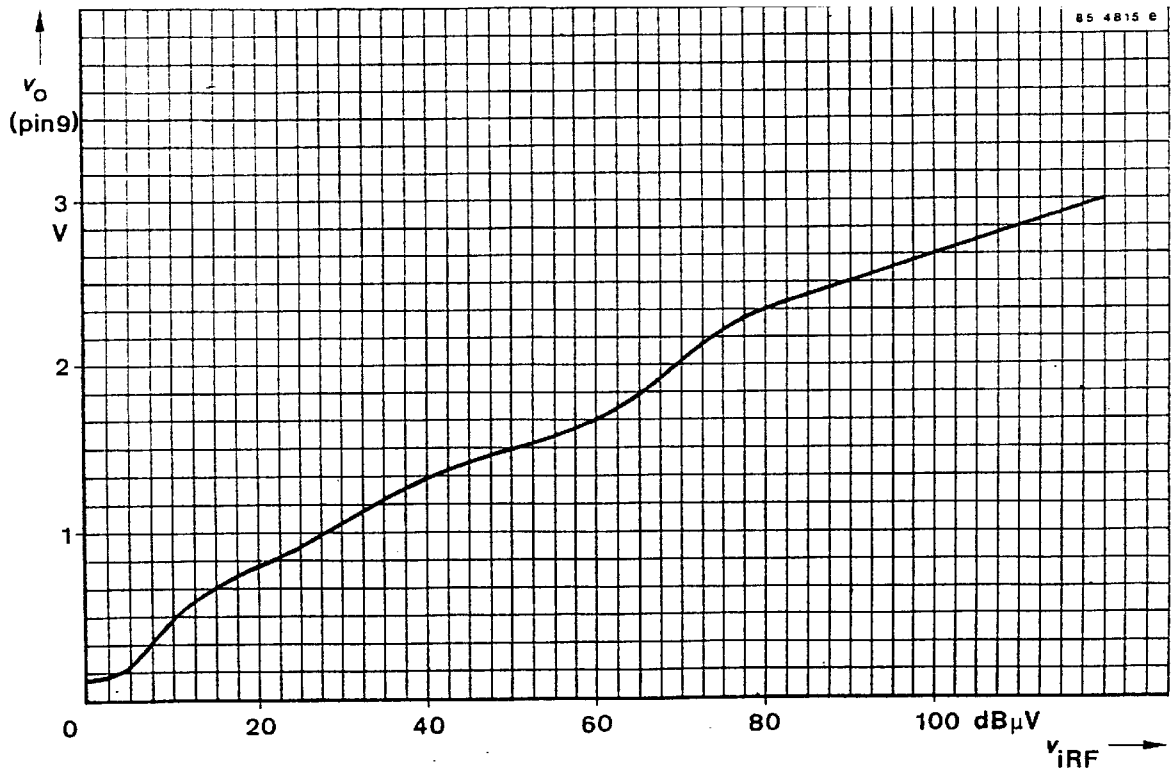


Figure 4.

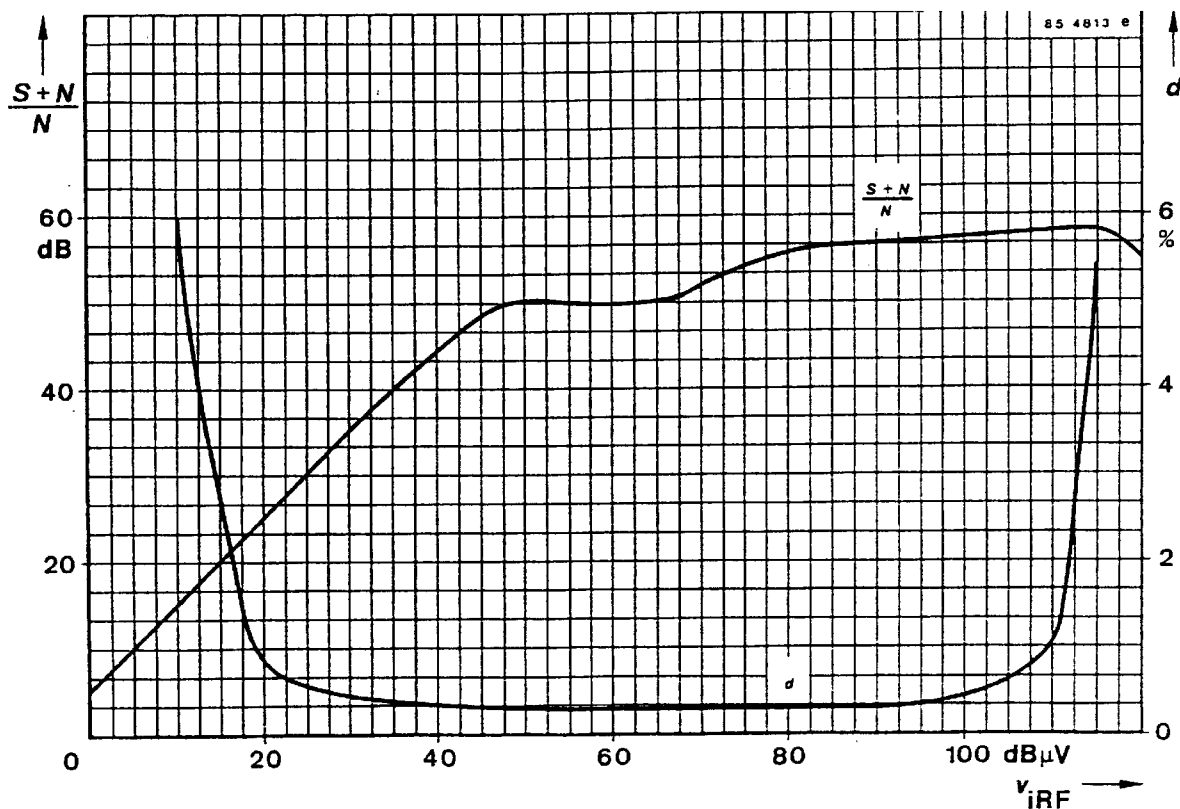
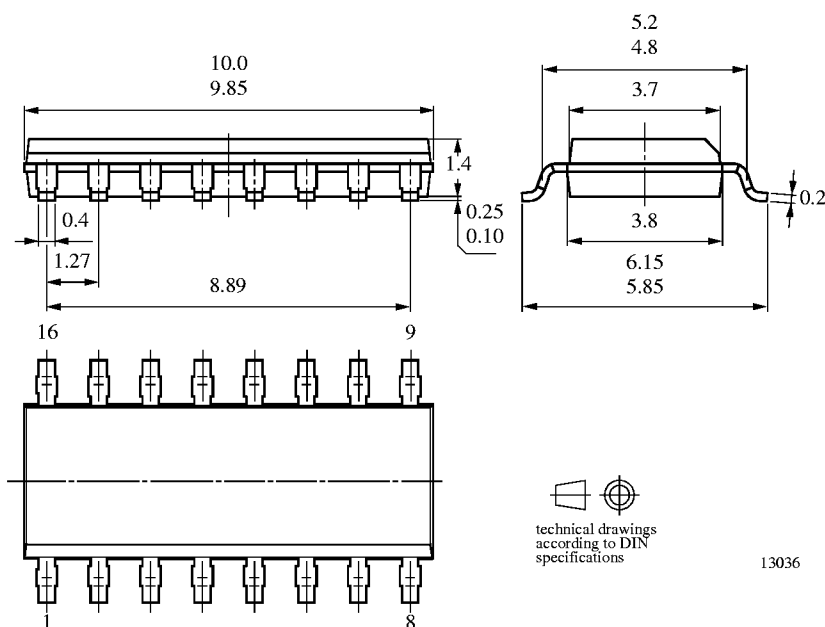


Figure 5.

Dimensions in mm

Package SO16
Dimensions in mm



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TEMIC Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2594, Fax number: 49 (0)7131 67 2423